

1000 Ω GaAs thin-film resistor die

Resistance: 1000 Ω (typical); Linear operating current: 0.04 A (typical); Maximum allowable current: 0.08 A (maximum). Plan-view die dimensions: 0.5 × 0.5 mm.



Electrical characteristics · TA = +25 °C

Parameter	Symbol	Minimum	Typical	Maximum	Value	Unit
Resistor count	-	-	-	-	1	-
Terminal count	-	-	-	-	2	-
Resistance	-	-	1000	-	-	Ω
Resistance tolerance	-	-	±5	-	-	%
Linear operating current	-	-	0.04	-	-	A

Absolute limits

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Maximum allowable current	-	-	-	0.08	A

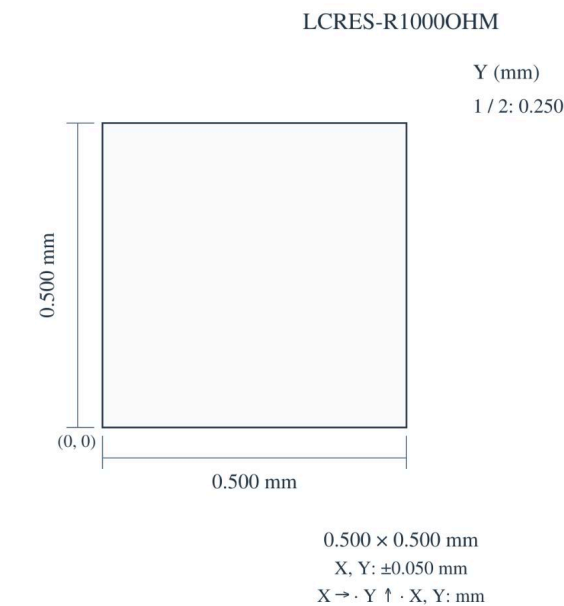
Environmental specifications

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Storage temperature	-	-65	-	150	°C
Operating temperature	-	-55	-	125	°C

Die dimensions

Parameter	Value	Unit
Plan-view die dimensions	0.5 × 0.5	mm

Mechanical Outline



All dimensions are in mm [in].

Bond-pad assignments

Pins	Symbol	Function	Notes
1, 2	IN/OUT	Reciprocal input/output	-
Die backside	GND	Ground	RF / DC GND

Current publication record · 1.1 · 2026-10-23. Specification tables updated. Replaces revision 1.0.

Die integration and bias sequencing

The die backside requires a reliable ground connection.

Mechanical reference scope

Source-based dimensional guide in mm. Partial information; not a complete fabrication or wire-bonding drawing.

Document notice

Specifications are subject to revision. Before design release, confirm the current document revision and product-specific requirements with LCRF. The approved quotation and order documentation define the supplied configuration.